

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Attorney Docket No. 040373/0300

#8/DK
6/10/02
Wills

Applicant: Toshiyuki HIROTA et al.

Title:

SEMICONDUCTOR DEVICE WITH HIGH- AND LOW-DENSITY REGIONS OF TRANSISTOR ELEMENTS ON SINGLE SEMICONDUCTOR SUBSTRATE, AND METHOD OF MANUFACTURING SUCH SEMICONDUCTOR DEVICE



Serial No.: 09/741,195

Filed: December 21, 2000

Examiner: Vu, Quang D.

Art Unit: 2811

Commissioner for Patents
Washington, D.C. 20231

Sir:

PROPOSED CHANGES TO THE DRAWINGS

Applicants propose to amend Figure 1, as shown in red on the attached copy. With the Examiner's approval, the changes will be made to the formal drawings in due course.

Respectfully submitted,

June 4, 2002
Date

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